

SANYO Semiconductors DATA SHEET

30C02MH — Low-Frequency General-Purpose Amplifier Applications

Applications

· Low-frequency Amplifier, high-speed switching, small motor drive.

Features

- · Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance): $R_{CE}(sat)$ typ=330m Ω [I_C=0.7A, I_B=35mA].
- · Ultrasmall package facilitates miniaturization in end products.
- · Small ON-resistance (Ron).

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		700	mA
Collector Current (Pulse)	ICP		1.4	Α
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm)	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Marking: CL

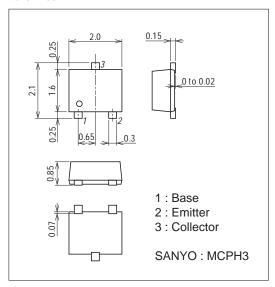
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Electrical Characteristics at Ta=25°C

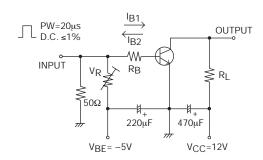
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	VCB=30V, IE=0A			100	nA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	hFE	V _{CE} =2V, I _C =50mA	300		800	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =50mA		540		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		3.3		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =200mA, I _B =10mA		85	190	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =200mA, I _B =10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0A	5			V
Turn-On Time	ton	See specified Test Circuit.		35		ns
Storage Time	t _{stg}	See specified Test Circuit.		255		ns
Fall Time	tf	See specified Test Circuit.		40		ns

Package Dimensions

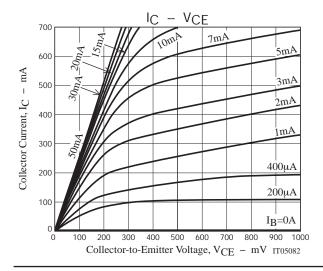
unit : mm (typ) 7019A-004

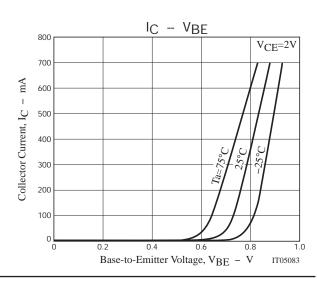


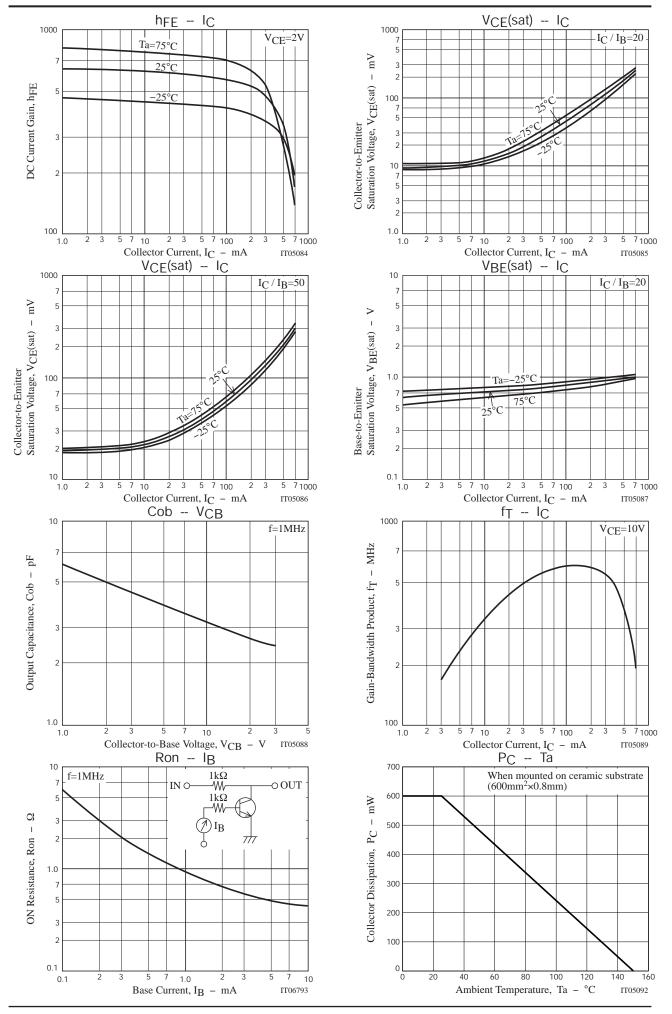
Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=300mA$







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